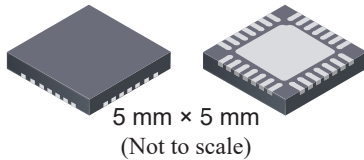


## Single LNB Supply and Control Voltage Regulator

### Features and Benefits

- 2-wire serial I<sup>2</sup>C™-compatible interface: control (write) and status (read)
- LNB voltages (16 programmable levels) compatible with all common standards
- Tracking switch-mode power converter for lowest dissipation
- Integrated converter switches and current sensing
- Output current limit of 900 mA typical, with 48 ms timer
- Static current limit circuit allows full current at startup and 13→18V output transition; reliably starts wide load range
- Push-pull output stage minimizes 13→18V and 18→13V output transition times for highly capacitive loads
- Adjustable rise/fall time via external timing capacitor
- Built-in tone oscillator, factory-trimmed to 22 kHz facilitates DiSEqC™ tone encoding, even at no-load
- Four methods of 22 kHz tone generation, via I<sup>2</sup>C™ data bits and/or external pin
- Filter bypass MOSFET minimizes losses during tone transmit
- 22 kHz tone detector facilitates DiSEqC™ 2.0 decoding
- Diagnostics for output voltage level, input supply UVLO, and DiSEqC™ tone output
- Auxiliary modulation input
- LNB overcurrent with timer
- Cable disconnect diagnostic

**Package: 28-pin QFN (suffix ET)**



### Description

Intended for analog and digital satellite receivers, this single low noise block converter regulator (LNBR) is a monolithic linear and switching voltage regulator, specifically designed to provide the power and the interface signals to an LNB down converter via coaxial cable. The A8290 requires few external components, with the boost switch and compensation circuitry integrated inside of the device. A high switching frequency is chosen to minimize the size of the passive filtering components, further assisting in cost reduction. The high levels of component integration ensure extremely low noise and ripple figures.

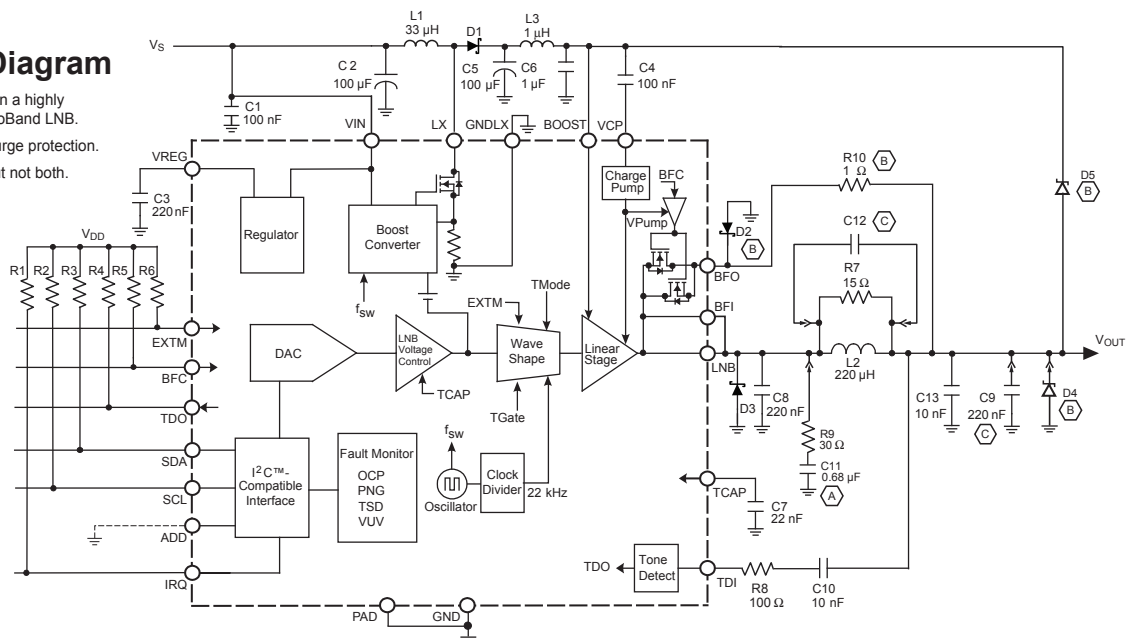
The A8290 has been designed for high efficiency, utilizing the Allegro™ advanced BCD process. The integrated boost switch has been optimized to minimize both switching and static losses. To further enhance efficiency, the voltage drop across the tracking regulator has been minimized.

The A8290 has integrated tone detection capability, to support full two-way DiSEqC™ communications. Several schemes are available for generating tone signals, all the way down to no-load, and using either the internal clock or an external time source. A DiSEqC™ filter bypass switch is also integrated, to minimize the output impedance during tone generation.

*Continued on the next page...*

### Functional Block Diagram

- (A) R9-C11 network is needed only when a highly inductive load is applied, such as ProBand LNB.
- (B) D2, D4, D5, and R10 are used for surge protection.
- (C) Either C12 or C9 should be used, but not both.



# A8290

# Single LNB Supply and Control Voltage Regulator

## Description (continued)

A comprehensive set of fault registers are provided, which comply with all the common standards, including: overcurrent, thermal shutdown, undervoltage, cable disconnect, power not good, and tone detect.

The device uses a 2-wire bidirectional serial interface, compatible with the I<sup>2</sup>C™ standard, that operates up to 400 kHz.

The A8290 is supplied in a lead (Pb) free 28-lead MLP/QFN.

## Selection Guide

Part Number	Packing <sup>a</sup>	Description
A8290SETTR-T <sup>b</sup>	7 in. reel, 1500 pieces/reel 12 mm carrier tape	ET package, MLP surface mount 0.90 mm nominal height



<sup>a</sup> Contact Allegro for additional packing options.

<sup>b</sup> Leadframe plating 100% matte tin.

## Absolute Maximum Ratings

Characteristic	Symbol	Conditions	Rating	Units
Load Supply Voltage, VIN pin	V <sub>IN</sub>		30	V
Output Current <sup>1</sup>	I <sub>OUT</sub>		Internally Limited	A
Output Voltage, BOOST pin			-0.3 to 33	V
Output Voltage, LNB, BFI, BFO pins		Surge <sup>2</sup>	-1 to 33	V
Output Voltage, LX pin			-0.3 to 30	V
Output Voltage, VCP pin			-0.3 to 41	V
Logic Input Voltage, EXTM and BFC pins			-0.3 to 5	V
Logic Input Voltage, other pins			-0.3 to 7	V
Logic Output Voltage			-0.3 to 7	V
Operating Ambient Temperature	T <sub>A</sub>		-20 to 85	°C
Junction Temperature	T <sub>J(max)</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to 150	°C

<sup>1</sup>Output current rating may be limited by duty cycle, ambient temperature, and heat sinking. Under any set of conditions, do not exceed the specified current ratings, or a junction temperature, T<sub>J</sub>, of 150°C.

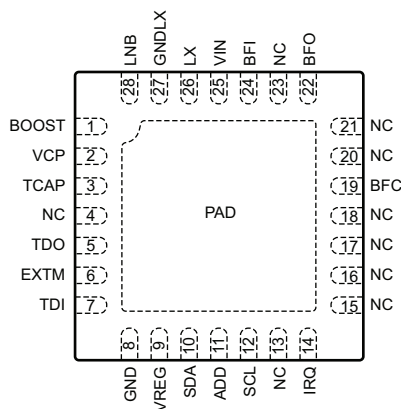
<sup>2</sup>Use Allegro recommended Application circuit.

## Package Thermal Characteristics\*

Package	R <sub>θJA</sub> (°C/W)	PCB
ET	32	4-layer

\* Additional information is available on the Allegro website.

**Device Pin-out Diagram**



(Top View)

**Terminal List Table**

Name	Number	Function
ADD	11	Address select
BFC	19	Bypass FET control
BFI	24	Bypass FET input (connect to LNB)
BFO	22	Bypass FET output
BOOST	1	Tracking supply voltage to linear regulator
EXTM	6	External modulation input
GND	8	Signal ground
GNDLX	27	Boost switch ground
IRQ	14	Interrupt request
LNB	28	Output voltage to LNB
LX	26	Inductor drive point
NC	4, 13, 15-18, 20, 21, 23	No connection
PAD	Pad	Exposed pad; connect to the ground plane, for thermal dissipation
SCL	12	I <sup>2</sup> C™-compatible clock input
SDA	10	I <sup>2</sup> C™ -compatible data input/output
TCAP	3	Capacitor for setting the rise and fall time of the LNB output
TDI	7	Tone detect input
TDO	5	Tone detect output
VCP	2	Gate supply voltage
VIN	25	Supply input voltage
VREG	9	Analog supply

**ELECTRICAL CHARACTERISTICS** at  $T_A = 25^\circ\text{C}$ ,  $V_{IN} = 8$  to  $16$  V, unless noted otherwise<sup>1</sup>

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
<b>General</b>						
Set-Point Accuracy, Load and Line Regulation	Err	Relative to selected $V_{LNB}$ target level, $I_{LOAD} = 0$ to $500$ mA	-3	-	3	%
Supply Current	$I_{IN(Off)}$	ENB bit = 0, LNB output disabled, $V_{IN} = 12$ V	-	-	10.0	mA
	$I_{IN(On)}$	ENB bit = 1, LNB output enabled, $I_{LOAD} = 0$ mA, $V_{IN} = 12$ V	-	-	19.0	mA
Boost Switch On Resistance	$R_{DS(on)BOOST}$	$I_{LOAD} = 500$ mA	-	300	600	m $\Omega$
Switching Frequency	$f_{SW}$		320	352	384	kHz
Switch Current Limit	$I_{LIMSW}$	$V_{IN} = 10$ V, $V_{OUT} = 20.3$ V	-	3.8	-	A
Linear Regulator Voltage Drop	$\Delta V_{REG}$	$V_{BOOST} - V_{LNB}$ , no tone signal, $I_{LOAD} = 500$ mA	600	800	1000	mV
TCAP Pin Current	$I_{CHG}$	TCAP capacitor (C7) charging	-12.5	-10	-7.5	$\mu$ A
	$I_{DISCHG}$	TCAP capacitor (C7) discharging	7.5	10	12.5	$\mu$ A
Output Voltage Rise Time <sup>2</sup>	$t_{r(VLNB)}$	For $V_{LNB}$ 13 $\rightarrow$ 18 V; $C_{TCAP} = 5.6$ nF, $I_{LOAD} = 500$ mA	-	500	-	$\mu$ s
Output Voltage Pull-Down Time <sup>2</sup>	$t_{r(VLNB)}$	For $V_{LNB}$ 18 $\rightarrow$ 13 V; $C_{LOAD} = 100$ $\mu$ F, $I_{LOAD} = 0$ mA	-	12.5	-	ms
Output Reverse Current	$I_{RLNB}$	ENB bit = 0, $V_{LNB} = 33$ V, BOOST capacitor (C5) fully charged	-	1	5	mA
Ripple and Noise on LNB Output <sup>3</sup>	$V_{rip,n(pp)}$	20 MHz BWL; reference circuit shown in Functional Block diagram; contact Allegro for additional information on application circuit board design	-	30	-	mV <sub>PP</sub>
<b>Protection Circuitry</b>						
Output Overcurrent Limit <sup>4</sup>	$I_{LIMLNB}$	$V_{BOOST} - V_{LNB} = 800$ mV	800	900	1000	mA
Overcurrent Disable Time	$t_{DIS}$		40	48	56	ms
VIN Undervoltage Lockout Threshold	$V_{UVLO}$	$V_{IN}$ falling	7.05	7.35	7.65	V
VIN Turn On Threshold	$V_{IN(th)}$	$V_{IN}$ rising	7.40	7.70	8.00	V
Undervoltage Hysteresis	$V_{UVLOHYS}$		-	350	-	mV
Thermal Shutdown Threshold <sup>2</sup>	$T_J$		-	165	-	$^\circ\text{C}$
Thermal Shutdown Hysteresis <sup>2</sup>	$\Delta T_J$		-	20	-	$^\circ\text{C}$
Power Not Good Flag Set	PNG <sub>SET</sub>	With respect to $V_{LNB}$	77	85	93	%
Power Not Good Flag Reset	PNG <sub>RESET</sub>	With respect to $V_{LNB}$	82	90	98	%
Power Not Good Hysteresis	PNG <sub>HYS</sub>	With respect to $V_{LNB}$	-	5	-	%
Cable Disconnect Boost Voltage	$V_{CAD}$	CADT bit = 1, ENB bit = 1, VSEL0 through VSEL3 = 1	22.0	22.8	23.5	V
Cable Disconnect Set	$V_{CADSET}$		20.16	21.00	21.84	V
Cable Disconnect Current Source	$I_{CADSRC}$	$V_{LNB} = 21.00$ V, $V_{BOOST} = 22.8$ V	1.0	1.75	2.5	mA

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**ELECTRICAL CHARACTERISTICS (continued) at  $T_A = 25^\circ\text{C}$ ,  $V_{IN} = 8$  to  $16\text{ V}$ , unless noted otherwise<sup>1</sup>**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
<b>Bypass FET</b>						
Bypass FET Control (BFC) Logic Input	$V_{BFC(H)}$		2.0	–	–	V
	$V_{BFC(L)}$		–	–	0.8	V
Input Leakage	$I_{BFCLKG}$		–1	–	1	$\mu\text{A}$
Bypass FET On Resistance	$R_{DS(on)}$	$I_{LOAD} = 500\text{ mA}$ , and $V_{BFC} = \text{Low}$ , or BFC2 bit = 1	–	0.5	1	$\Omega$
Turn On/Off Delay <sup>2</sup>	$t_{D(ON/OFF)}$	$V_{BFC} = \text{Low}$ , or BFC2 bit = 1	–	650	–	$\mu\text{s}$
<b>Tone</b>						
Tone Frequency	$f_{TONE}$		20	22	24	kHz
Tone Amplitude, Peak-to-Peak	$V_{TONE(pp)}$	$I_{LOAD} = 0$ to $500\text{ mA}$ , $C_{LOAD} = 750\text{ nF}$	400	620	800	mV
Tone Duty Cycle	$DC_{TONE}$	$I_{LOAD} = 0$ to $500\text{ mA}$ , $C_{LOAD} = 750\text{ nF}$	40	50	60	%
Tone Rise Time	$t_{rTONE}$	$I_{LOAD} = 0$ to $500\text{ mA}$ , $C_{LOAD} = 750\text{ nF}$	5	10	15	$\mu\text{s}$
Tone Fall Time	$t_{fTONE}$	$I_{LOAD} = 0$ to $500\text{ mA}$ , $C_{LOAD} = 750\text{ nF}$	5	10	15	$\mu\text{s}$
EXTM Logic Input	$V_{EXTM(H)}$		2.0	–	–	V
	$V_{EXTM(L)}$		–	–	0.8	V
EXTM Input Leakage	$I_{EXTMLKG}$		–1	–	1	$\mu\text{A}$
<b>Tone Detector</b>						
Tone Detect Input Amplitude Receive, Peak-to-Peak	$V_{TDR(pp)}$	$f_{TONE} = 22\text{ kHz}$ sine wave, $TMODE = 0$	300	–	–	mV
Tone Detect Input Amplitude Transmit, Peak-to-Peak	$V_{TDT(pp)Int}$	$f_{TONE} = 22\text{ kHz}$ sine wave, using internal tone (options 1 and 2, in figure 2)	400	–	–	mV
	$V_{TDT(pp)Ext}$	$f_{TONE} = 22\text{ kHz}$ sine wave, using external tone (options 3 and 4, in figure 2)	300	–	–	mV
Tone Reject Input Amplitude, Peak-to-Peak	$V_{TRI(pp)}$	$f_{TONE} = 22\text{ kHz}$ sine wave	–	–	100	mV
Frequency Capture	$f_{TDI}$	600 mVpp sine wave	17.6	–	26.4	kHz
Input Impedance <sup>2</sup>	$Z_{TDI}$		–	8.6	–	k $\Omega$
TDO Output Voltage	$V_{TDO(L)}$	Tone present, $I_{LOAD} = 3\text{ mA}$	–	–	0.4	V
TDO Output Leakage	$I_{TDOLKG}$	Tone absent, $V_{TDO} = 7\text{ V}$	–	–	10	$\mu\text{A}$
<b>I<sup>2</sup>C™-Compatible Interface</b>						
Logic Input (SDA, SCL) Low Level	$V_{SCL(L)}$		–	–	0.8	V
Logic Input (SDA, SCL) High Level	$V_{SCL(H)}$		2.0	–	–	V
Logic Input Hysteresis	$V_{I2CIHYS}$		–	150	–	mV
Logic Input Current	$I_{I2CI}$	$V_{I2CI} = 0$ to $7\text{ V}$	–10	$<\pm 1.0$	10	$\mu\text{A}$
Logic Output Voltage SDA and IRQ	$V_{I2COut(L)}$	$I_{LOAD} = 3\text{ mA}$	–	–	0.4	V
Logic Output Leakage SDA and IRQ	$V_{I2CLKG}$	$V_{I2COut} = 0$ to $7\text{ V}$	–	–	10	$\mu\text{A}$
SCL Clock Frequency	$f_{CLK}$		–	–	400	kHz
Output Fall Time	$t_{fI2COut}$	$V_{I2COut(H)}$ to $V_{I2COut(L)}$	–	–	250	ns
Bus Free Time Between Stop/Start	$t_{BUF}$		1.3	–	–	$\mu\text{s}$
Hold Time Start Condition	$t_{HD:STA}$		0.6	–	–	$\mu\text{s}$
Setup Time for Start Condition	$t_{SU:STA}$		0.6	–	–	$\mu\text{s}$

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## ELECTRICAL CHARACTERISTICS (continued) at $T_A = 25^\circ\text{C}$ , $V_{IN} = 8$ to $16$ V, unless noted otherwise<sup>1</sup>

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
<b>I<sup>2</sup>C™-Compatible Interface (continued)</b>						
SCL Low Time	$t_{LOW}$		1.3	–	–	$\mu\text{s}$
SCL High Time	$t_{HIGH}$		0.6	–	–	$\mu\text{s}$
Data Setup Time	$t_{SU:DAT}$		100	–	–	ns
Data Hold Time	$t_{HD:DAT}$	For $t_{HD:DAT}(\text{min})$ , the master device must provide a hold time of at least 300 ns for the SDA signal in order to bridge the undefined region of the SCL signal falling edge	0	–	900	ns
Setup Time for Stop Condition	$t_{SU:STO}$		0.6	–	–	$\mu\text{s}$
<b>I<sup>2</sup>C™ Address Setting</b>						
ADD Voltage for Address 0001,000	Address1		0	–	0.7	V
ADD Voltage for Address 0001,001	Address2		1.3	–	1.7	V
ADD Voltage for Address 0001,010	Address3		2.3	–	2.7	V
ADD Voltage for Address 0001,011	Address4		3.3	–	5.0	V

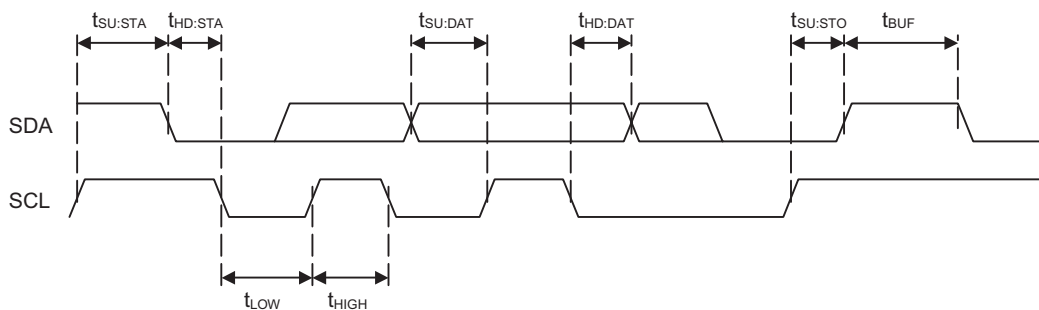
<sup>1</sup>Operation at 16 V may be limited by power loss in the linear regulator.

<sup>2</sup>Guaranteed by worst case process simulations and system characterization. Not production tested.

<sup>3</sup>LNB output ripple and noise are dependent on component selection and PCB layout. Refer to the Application Schematic and PCB layout recommendations. Not production tested.

<sup>4</sup>Current from the LNB output may be limited by the choice of Boost components.

### I<sup>2</sup>C™ Interface Timing Diagram



## Functional Description

### Protection

The A8290 has a wide range of protection features and fault diagnostics which are detailed in the Status Register section.

### Boost Converter/Linear Regulator

The A8290 solution contains a tracking current-mode boost converter and linear regulator. The boost converter tracks the requested LNB voltage to within 800 mV, to minimize power dissipation. Under conditions where the input voltage,  $V_{\text{BOOST}}$ , is greater than the output voltage,  $V_{\text{LNB}}$ , the linear regulator must drop the differential voltage. When operating in these conditions, care must be taken to ensure that the safe operating temperature range of the A8290 is not exceeded.

The boost converter operates at 352 kHz typical: 16 times the internal 22 kHz tone frequency. All the loop compensation, current sensing, and slope compensation functions are provided internally.

The A8290 has internal pulse-by-pulse current limiting on the boost converter and dc current limiting on the LNB output to protect the IC against short circuits. When the LNB output is shorted, the LNB output current is limited to 900 mA typical, and the IC will be shut down if the overcurrent condition lasts for more than 48 ms. If this occurs, the A8290 must be reenabled for normal operation. The system should provide sufficient time between successive restarts to limit internal power dissipation; a minimum of 5 s is recommended.

At extremely light loads, the boost converter operates in a pulse-skipping mode. Pulse skipping occurs when the BOOST voltage rises to approximately 450 mV above the BOOST target output voltage. Pulse skipping stops when the BOOST voltage drops 200 mV below the pulse skipping level.

In the case that two or more set top box LNB outputs are connected together by the customer (e.g., with a splitter), it is possible that one output could be programmed at a higher voltage than the other. This would cause a voltage on one output that is higher than its programmed voltage (e.g., 19 V on the output of a 13 V programmed voltage). The output with the highest voltage will effectively turn off the other outputs. As soon as this voltage is reduced below the value of the other outputs, the A8290 output will auto-recover to their programmed levels.

**Charge Pump.** Generates a supply voltage above the internal

tracking regulator output to drive the linear regulator control.

**Slew Rate Control.** During either start-up, or when the output voltage at the LNB pin is transitioning, the output voltage rise and fall times can be set by the value of the capacitor connected from the TCAP pin to GND ( $C_{\text{TCAP}}$  or C7 in the Applications Schematic). Note that during start-up, the BOOST pin is pre-charged to the input voltage minus a voltage drop. As a result, the slew rate control for the BOOST pin occurs from this voltage.

The value of  $C_{\text{TCAP}}$  can be calculated using the following formula:

$$C_{\text{TCAP}} = (I_{\text{TCAP}} \times 6) / \text{SR} ,$$

where SR is the required slew rate of the LNB output voltage, in V/s, and  $I_{\text{TCAP}}$  is the TCAP pin current specified in the datasheet. The recommended value for  $C_{\text{TCAP}}$ , 10 nF, should provide satisfactory operation for most applications. However, in some cases, it may be necessary to increase the value of  $C_{\text{TCAP}}$  to avoid activating the current limit of the LNB output.

One such situation is when two set-top boxes are connected in parallel. If this is the case, the following formula can be used to calculate a larger value for  $C_{\text{TCAP}}$ :

$$C_{\text{TCAP}} \geq (I_{\text{TCAP}} \times 6)(2 \times C_{\text{BOOST}}) / I_{\text{LIMLNB}} ,$$

$$C_{\text{TCAP}} \geq (10 \mu\text{A} \times 6)(2 \times 100 \mu\text{F}) / 800 \text{ mA} = 15 \text{ nF} .$$

The minimum value of  $C_{\text{TCAP}}$  is 2.2nF. There is no theoretical maximum value of  $C_{\text{TCAP}}$ , however, too large a value will probably cause the voltage transition specifications to be exceeded. Tone generation is unaffected by the value of  $C_{\text{TCAP}}$ .

**Pull-Down Rate Control.** In applications that have to operate at very light loads and that require large load capacitances (in the order of tens to hundreds of microfarads), the output linear stage provides approximately 40 mA of pull-down capability. This ensures that the output volts are ramped from 18 V to 13 V in a reasonable amount of time.

### ODT (Overcurrent Disable Time)

If the LNB output current exceeds 900 mA, typical, for more than 48 ms, then the LNB output will be disabled and the OCP bit will be set. See figure 1, a timing diagram for this function.

## Short Circuit Handling

If the LNB output is shorted to ground, the LNB output current will be clamped to 900 mA, typical. If the short circuit condition lasts for more than 48 ms, the A8290 will be disabled and the OCP bit will be set.

## Auto-Restart

After a short circuit condition occurs, the host controller should periodically reenable the A8290 to check if the short circuit has been removed. Consecutive startup attempts should allow at least 5 s of delay between restarts.

## In-Rush Current

At start-up or during an LNB reconfiguration event, a transient surge current above the normal DC operating level can be provided by the A8290. This current increase can be as high as 900 mA, typical, for as long as required, up to a maximum of 48 ms.

## DC current

The A8290 can handle up to 700 mA per channel individually, during continuous operation.

## Tone Detection

A 22 kHz tone detector is provided in the A8290 solution. The detector extracts the tone signal and provides it as an open-drain signal on the TDO pin. The maximum tone out error is  $\pm 1$  tone cycle, and the maximum tone out delay with respect to the input is 1 tone cycle. Detection thresholds are given in table 1.

## Tone Generation

The A8290 solution offers four options for tone generation, providing maximum flexibility to cover every application. The

**Table 1. Detection Thresholds for Tone Generation Options**

Option (Fig. 1)	Transmit				Receive	
	1	2	3	4	n.a.	n.a.
TMODE	1	1	0	0	0	1
TGATE	Control 0/1	1	Control 0/1	1	At least one must be 0 to prevent tone transmission	
EXTM	1	Control 0/1	22 kHz logic signal, continuous	Control gated 22 kHz logic signal		
Guaranteed Detection Threshold (mV <sub>PP</sub> )	400	400	300	300	300	400
Rejection Threshold (mV <sub>PP</sub> )	100	100	100	100	100	100

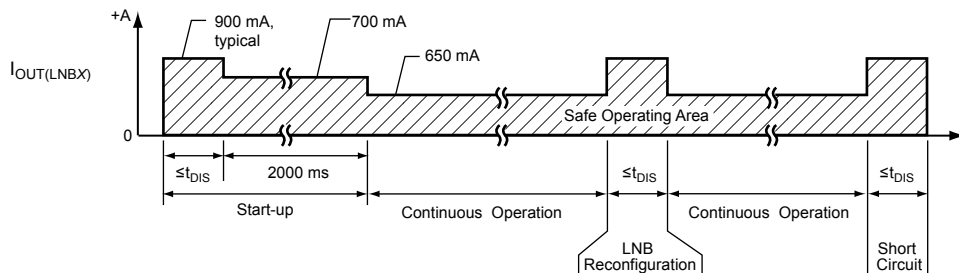
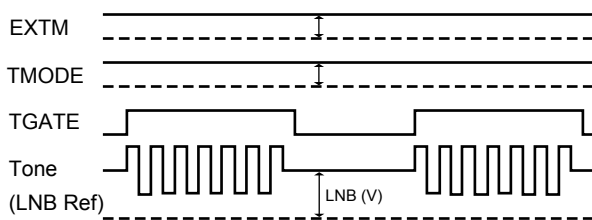


Figure 1. ODT (Overcurrent Disable Timing) Mode Timing Diagram

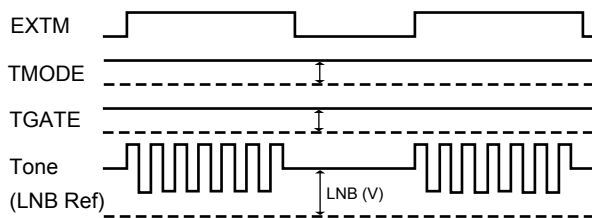


EXTM pin (external modulation), in conjunction with the I<sup>2</sup>C™ control bits: TMODE (tone modulation) and TGATE (tone gate), provide the necessary control. The TMODE bit controls whether the tone source is either internal or external (via the EXTM pin). Both the EXTM pin and TGATE bit determine the 22 kHz control, whether gated or clocked.

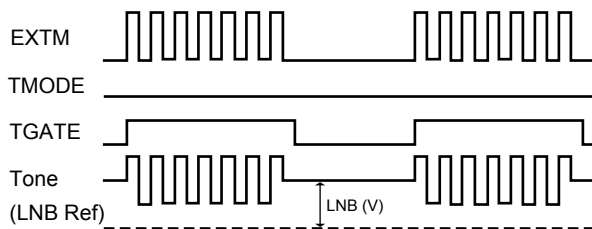
Four options for tone generation are shown in figure 2. Note that when using option 4, when EXTM stops clocking, the LNB volts park at the LNB voltage, either plus or minus half the tone signal amplitude, depending on the state of EXTM. For example, if the EXTM is held low, the LNB dc voltage is the LNB programmed voltage minus 325 mV (typical).



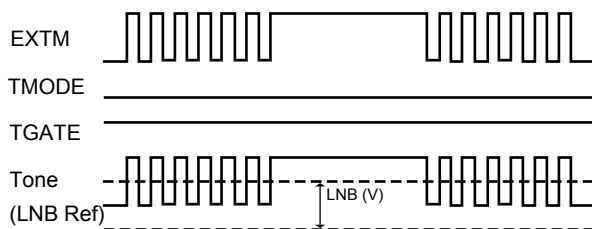
Option 1 – Use internal tone, gated by the TGATE bit.



Option 2 – Use internal tone, gated by the EXTM pin.



Option 3 – Use external tone, gated by the TGATE bit.



Option 4 – Use external tone.

Figure 2. Options for tone generation

With any of the four options, when a tone signal is generated, TDET is set in the status register. When the internal tone is used (options 1 or 2), the minimum tone detect amplitude is 400 mV, and when an external tone is used (options 3 or 4), the minimum tone detection amplitude is 300 mV.

### DiSEqC™ Bypass MOSFET

A pair of N-channel MOSFETs are connected in parallel (source to drain and drain to source) to provide a low source output impedance during tone transmission.

The MOSFETs are enabled either via the BFC input pin (active low) or by setting the BFC2 bit to 1 in the Control register. When the BFC pin is used instead of I<sup>2</sup>C™ control, it is not latched; a logic high or low turns the FET off or on. When the I<sup>2</sup>C™-compatible interface is used, the BFC pin is not connected, but the pull up resistor R5 must be present.

### I<sup>2</sup>C™-Compatible Interface

This is a serial interface that uses two bus lines, SCL and SDA, to access the internal Control and Status registers of the A8290. Data is exchanged between a microcontroller (master) and the A8290 (slave). The clock input to SCL is generated by the master, while SDA functions as either an input or an open drain output, depending on the direction of the data.

### Timing Considerations

The control sequence of the communication through the I<sup>2</sup>C™-compatible interface is composed of several steps in sequence:

1. Start Condition. Defined by a negative edge on the SDA line, while SCL is high.
2. Address Cycle. 7 bits of address, plus 1 bit to indicate read (1) or write (0), and an acknowledge bit. The first five bits of the address are fixed as: 00010. The four optional addresses, defined by the remaining two bits, are selected by the ADD input. The address is transmitted MSB first.
3. Data Cycles.
  - Write – 6 bits of data and 2 bits for addressing four internal control registers, followed by an acknowledge bit. See Control Register section for more information.
  - Read – Two status registers, where register 1 is read first, followed by register 2, then register 1, and so on. At the start of any read sequence, register 1 is always read first. Data is transmitted MSB first.
4. Stop Condition. Defined by a positive edge on the SDA line, while SCL is high. Except to indicate a Start or Stop condition, SDA must be stable while the clock is high. SDA can only be changed while SCL is low. It is possible for the Start or Stop condition to occur at any time during a data transfer. The A8290 always responds by resetting the data transfer sequence.

The Read/Write bit is used to determine the data transfer direction. If the Read/Write bit is high, the master reads the contents of register 1, followed by register 2 if a further read is performed. If the Read/Write bit is low, the master writes data to one of the two Control registers. Note that multiple writes are not permitted. All write operations must be preceded with the address.

The Acknowledge bit has two functions. It is used by the master to determine if the slave device is responding to its address and data, and it is used by the slave when the master is reading data back from the slave. When the A8290 decodes the 7-bit address field as a valid address, it responds by pulling SDA low during the ninth clock cycle.

During a data write from the master, the A8290 also pulls SDA low during the clock cycle that follows the data byte, in order to indicate that the data has been successfully received. In both cases, the master device must release the SDA line before the ninth clock cycle, in order to allow this handshaking to occur.

During a data read, the A8290 acknowledges the address in the same way as in the data write sequence, and then retains control of the SDA line and send the data from register 1 to the master. On completion of the eight data bits, the A8290 releases the SDA line before the ninth clock cycle, in order to allow the master to acknowledge the data. If the master holds the SDA line low during this Acknowledge bit, the A8290 responds by sending the data from register 2 to the master. Data bytes continue to be sent to the master until the master releases the SDA line during the Acknowledge bit. When this is detected, the A8290 stops sending data and waits for a stop signal.

### Interrupt Request

The A8290 also provides an interrupt request pin, IRQ, which is an open-drain, active-low output. This output may be connected to a common IRQ line with a suitable external pull-up and can be used with other I<sup>2</sup>C™-compatible devices to request attention from the master controller.

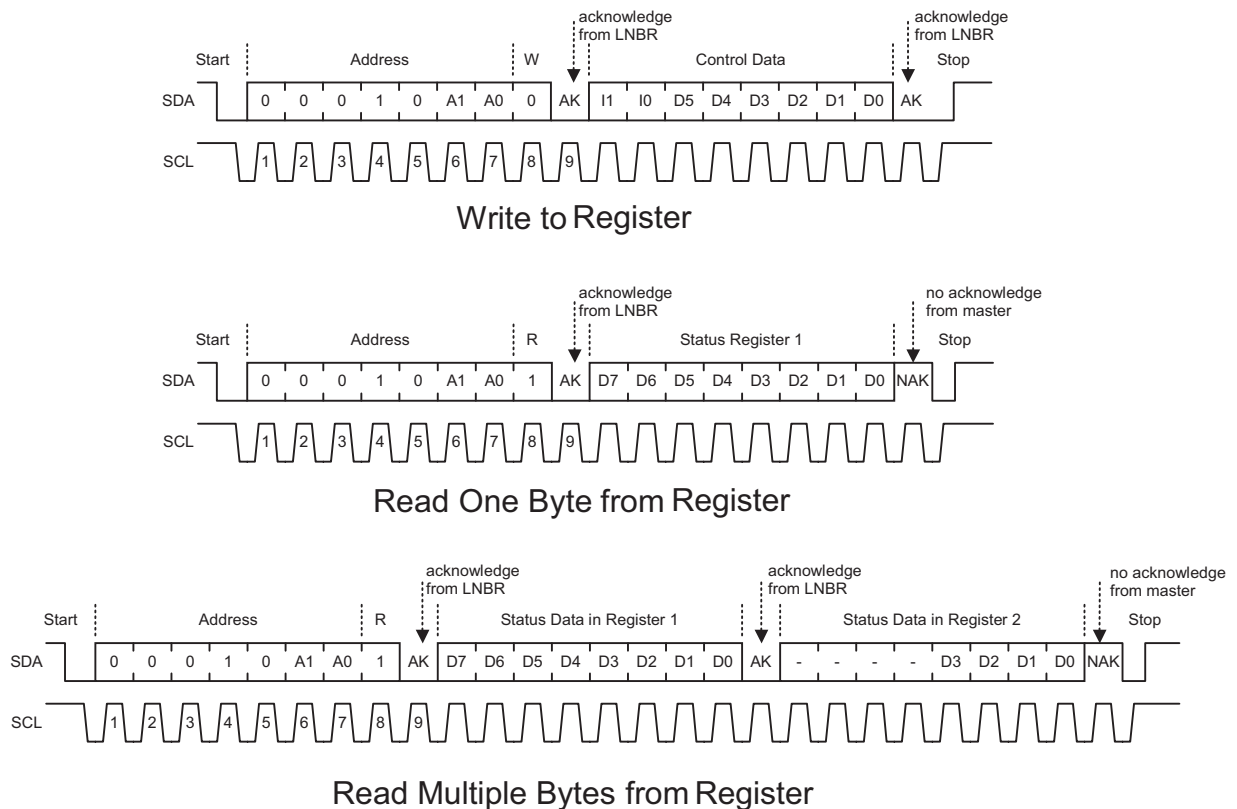


Figure 3. I<sup>2</sup>C™ Interface. Read and write sequences.

The IRQ output becomes active when either the A8290 first recognizes a fault condition, or at power-on, when the main supply,  $V_{IN}$ , and the internal logic supply,  $V_{REG}$ , reach the correct operating conditions. It is only reset to inactive when the I<sup>2</sup>C™ master addresses the A8290 with the Read/Write bit set (causing a read). Fault conditions are indicated by the TSD, VUV, and OCP bits and are latched in the Status register. See the Status register section for full description.

The DIS, PNG, CAD and TDET status bits do not cause an interrupt. All these bits are continually updated, apart from the DIS bit, which changes when the LNB is either disabled, intentionally or due to a fault, or is enabled.

When the master recognizes an interrupt, it addresses all slaves connected to the interrupt line in sequence, and then reads

the status register to determine which device is requesting attention. The A8290 latches all conditions in the Status register until the completion of the data read. The action at the resampling point is further defined in the Status Register section. The bits in the Status register are defined such that the all-zero condition indicates that the A8290 is fully active with no fault conditions.

When  $V_{IN}$  is initially applied, the I<sup>2</sup>C™-compatible interface does not respond to any requests until the internal logic supply  $V_{REG}$  has reached its operating level. Once  $V_{REG}$  has reached this point, the IRQ output goes active, and the VUV bit is set. After the A8290 acknowledges the address, the IRQ flag is reset. After the master reads the status registers, the registers are updated with the VUV reset.

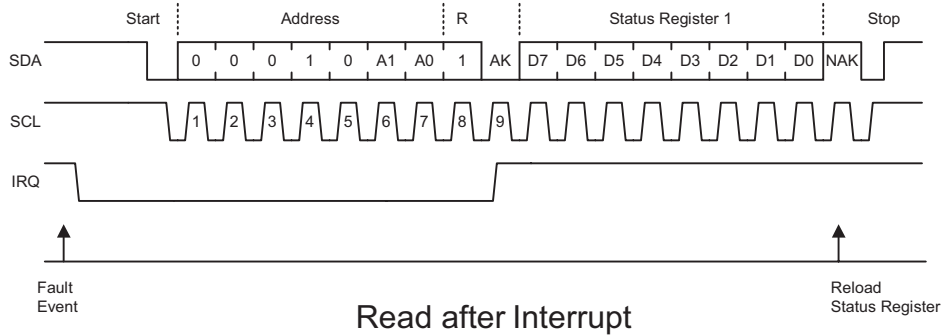


Figure 4. I<sup>2</sup>C™ Interface. Read sequences after interrupt request.

## Control Registers (I<sup>2</sup>C™-Compatible Write Register)

All main functions of the A8290 are controlled through the I<sup>2</sup>C™-compatible interface via the 8-bit Control registers. As the A8290 contains numerous control options, it is necessary to have two control registers. Each register contains up to 6 bits of data (bit

0 to bit 5), followed by 2 bits for the register address (bit 6 and bit 7). The power-up states for the control functions are all 0s.

The following tables define the control bits for each address and the settings for output voltage:

**Table 2. Control Register Address (I1, I0) = 00**

Bit	Name	Function
0	VSEL0	See table 4, Output Voltage Amplitude Selection
1	VSEL1	
2	VSEL2	
3	VSEL3	0: LNB = Low range 1: LNB = High range
4	ODT	1 (recommended): The ODT functions are always enabled, but setting 1 recommended at all times.
5	ENB	0: Disable LNB Output 1: Enable LNB Output
6	I0	Address Bit: 0
7	I1	Address Bit: 0

- Bit 0 VSEL0 These three bits provide incremental control over the voltage on the LNB output.
- Bit 1 VSEL1 The available voltages provide the necessary levels for all the common standards
- Bit 2 VSEL2 plus the ability to add line compensation in increments of 333 mV. The voltage levels are defined in table 4, Output Voltage Amplitude Selection.
- Bit 3 VSEL3 Switches between the low level and high level output voltages on the LNB output. 0 selects the low level voltage and 1 selects the high level. The low-level center voltage is 12.709 V nominal and the high level is 18.042 V nominal. These may be increased in steps of 333 mV using the VSEL2, VSEL1 and VSEL0 control register bits.
- Bit 4 ODT The overcurrent disable timer is always enabled
- Bit 5 ENB Enables the LNB output. When set to 1 the LNB output is switched on. When set to 0, the LNB output is disabled.
- Bit 6 I0 Address
- Bit 7 I1 Address

**Table 3. Control Register Address (I1, I0) = 10**

Bit	Name	Function
0	TMODE	0: External Tone 1: Internal Tone
1	TGATE	0: Tone Gated Off 1: Tone Gated On
2	CADT	0: Cable Disconnect Test Off 1: Cable Disconnect Test On
3	-	Not Used
4	-	Not Used
5	BFC2	0: Bypass MOSFET Off 1: Bypass MOSFET On
6	I0	Address Bit: 0
7	I1	Address Bit: 1

- Bit 0 TMODE Tone Mode. Selects between the use of an external 22 kHz logic signal or the use of the internal 22 kHz oscillator to control the tone generation on the LNB output. A 0 selects the external tone and a 1 selects the internal tone. See the Tone Generation section for more information
- Bit 1 TGATE Tone Gate. Allows either the internal or external 22 kHz tone signals to be gated, unless the EXTM is selected for gating. When set to 0, the selected tone (via TMODE) is off. When set to 1, the selected tone is on. See Tone Generation Section for more information.
- Bit 2 CADT Cable Disconnect Test. To perform this test, set bits CADT, ENB, and VSEL0 through VSEL3 through the I<sup>2</sup>C™-compatible interface. During this test, the LNB linear regulator is disabled, a 1 mA current source between the BOOST output and the LNB output is enabled, and the BOOST voltage is increased to 22.8 V. After these conditions are set, if the LNB voltage is above 21 V, it is assumed that the coaxial cable connection between the LNBR output and the LNB head has been disconnected. In this case, the CAD bit is set in the status register. If there is a load on the LNB pin, then the LNB voltage will decrease proportionally to the load current. If the LNB volts drop below 19.95 V, it is assumed that the coax cable is connected and the CAD bit in the status register is set to 0.
- Bit 3 – Not Used.
- Bit 4 – Not Used.
- Bit 5 BFC2 Bypass MOSFET Control. When set to 1, the internal bypass MOSFETs are enabled. A 0 disables the bypass MOSFETs.
- Bit 6 I0 Address.
- Bit 7 I1 Address.

**Table 4. Output Voltage Amplitude Selection**

VSEL3	VSEL2	VSEL1	VSEL0	LNB (V)
0	0	0	0	12.709
0	0	0	1	13.042
0	0	1	0	13.375
0	0	1	1	13.709
0	1	0	0	14.042
0	1	0	1	14.375
0	1	1	0	14.709
0	1	1	1	15.042
1	0	0	0	18.042
1	0	0	1	18.375
1	0	1	0	18.709
1	0	1	1	19.042
1	1	0	0	19.375
1	1	0	1	19.709
1	1	1	0	20.042
1	1	1	1	20.375

### Status Registers (I<sup>2</sup>C™-Compatible Read Register)

The main fault conditions: overcurrent (OCP), under voltage (VUV) and overtemperature (TSD), are all indicated by setting the relevant bits in the Status registers. In all fault cases, once the bit is set, it remains latched until the A8290 is read by the I<sup>2</sup>C™ master, assuming the fault has been resolved.

The current status of the LNB output is indicated by the disable bit, DIS. The DIS bit is set when either a fault occurs or if the LNB is disabled intentionally. This bit is latched, and is reset when the LNB is commanded on again. The power not good (PNG), tone detect (TDET), and cable disconnected (CAD) flags are the only bits which may be reset without an I<sup>2</sup>C™ read sequence. Table 5 summarizes the condition of each bit when set and how it is reset.

As the A8290 has a comprehensive set of status reporting bits,

it is necessary to have two Status registers. When performing a multiple read function, register 1 is read followed by register 2, then register 1 again and so on. Whenever a new read function is performed, register 1 is always read first.

The normal sequence of the master in a fault condition will be to detect the fault by reading the Status registers, then rereading the Status registers until the status bit is reset indicating the fault condition is reset. The fault may be detected either by continuously polling, by responding to an interrupt request (IRQ), or by detecting a fault condition externally and performing a diagnostic poll of all slave devices. Note that the fully-operational condition of the Status registers is all 0s, to simplify checking of the Status bit.

**Table 5. Status Register Bit Setting**

Status Bit	Function	Set	Reset Condition
CAD	Cable disconnected	Non-latched	Cable disconnect test off or cable connected
DIS	LNB disabled, either intentionally or due to fault	Latched	LNB enabled and no fault
OCP	Overcurrent	Latched	I <sup>2</sup> C™ read and fault removed
PNG	Power not good	Non-latched	LNB volts in range
TDET	Tone detect	Non-latched	Tone removed
TSD	Thermal shutdown	Latched	I <sup>2</sup> C™ read and fault removed
VUV	Undervoltage	Latched	I <sup>2</sup> C™ read and fault removed

**Table 6. Status Register 1**

Bit	Name	Function
0	DIS	LNB output disabled
1	–	Not Used
2	OCP	Overcurrent
3	–	Not Used
4	PNG	Power Not Good
5	–	Not Used
6	TSD	Thermal Shutdown
7	VUV	V <sub>IN</sub> Undervoltage

- Bit 0 DIS LNB Output Disabled. DIS is used to indicate the current condition of the LNB output. At power-on, or if a fault condition occurs, DIS will be set. This bit changing to 1 does not cause the IRQ to activate because the LNB output may be disabled intentionally by the I<sup>2</sup>C™ master. This bit will be reset at the end of a write sequence if the LNB output is enabled.
- Bit 1 – Not used.
- Bit 2 OCP Overcurrent. If the LNB output detects an overcurrent condition, for greater than 48 ms, the LNB output will be disabled. The OCP bit will be set to indicate that an overcurrent has occurred and the disable bit, DIS, will be set. The Status register is updated on the rising edge of the 9<sup>th</sup> clock pulse in the data read sequence, where the OCP bit is reset in all cases, allowing the master to reenable the LNB output.
- Bit 3 – Not used.
- Bit 4 PNG Power Not Good. Set to 1 when the LNB voltage is below 85% of the programmed voltage. The PNG bit is reset when the LNB voltage is within 90% of the programmed LNB voltage. PNG is always active so, if the LNB output is disabled, then PNG will be a logic 1. At power-up, PNG reports a logic 1 until the LNB output is enabled and within 90% of the programmed LNB voltage.
- Bit 5 – Not used.
- Bit 6 TSD Thermal shutdown. 1 indicates that the A8290 has detected an overtemperature condition and has disabled the LNB output. The disable bit, DIS, will also be set. The status of the overtemperature condition is sampled on the rising edge of the 9<sup>th</sup> clock pulse in the data read sequence. If the condition is no longer present, then the TSD bit will be reset, allowing the master to reenable the LNB output if required. If the condition is still present, then the TSD bit will remain at 1.
- Bit 7 VUV Undervoltage Lockout. 1 indicates that the A8290 has detected that the input supply, V<sub>IN</sub> is, or has been, below the minimum level and an undervoltage lockout has occurred disabling the LNB outputs. The disable bit, DIS, will also be set and the A8290 will not reenable the output until so instructed by writing the relevant bit into the control registers. The status of the undervoltage condition is sampled on the rising edge of the 9<sup>th</sup> clock pulse in the data read sequence. If the condition is no longer present, then the VUV bit will be reset allowing the master to reenable the LNB output if required. If the condition is still present, then the VUV bit will remain at 1.



Table 7. Status Register 2

Bit	Name	Function
0	CAD	Cable Disconnected
1	–	Not Used
2	TDET	Tone Detect
3	–	Not Used
4	–	Not Used
5	–	Not Used
6	–	Not Used
7	–	Not Used

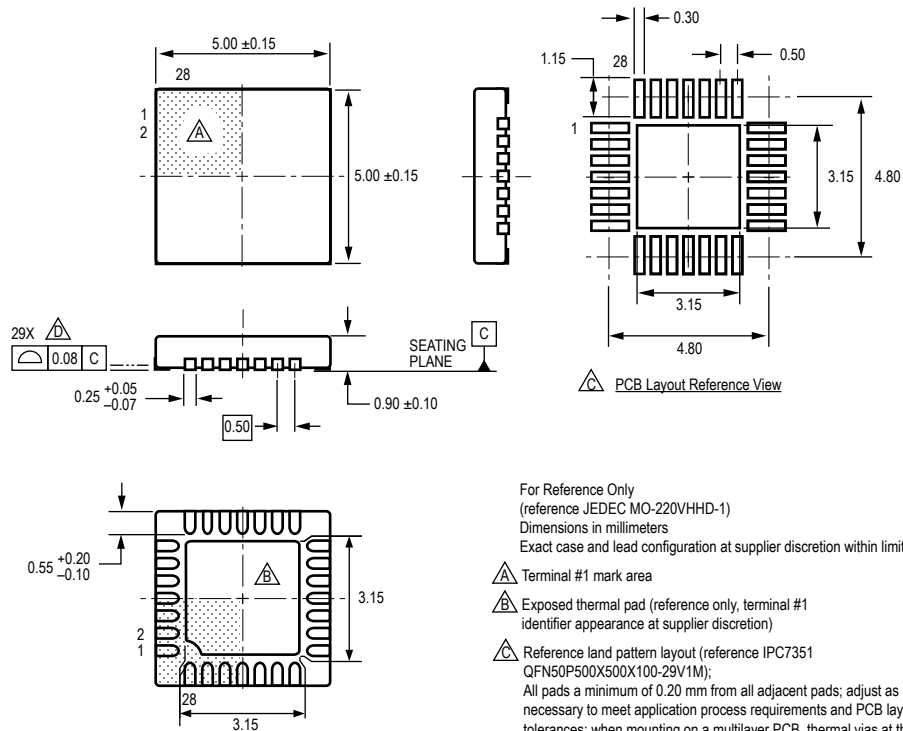
- Bit 0 CAD Cable between LNB and the LNB head is disconnected. When cable disconnect test mode is applied, the LNB linear regulator is disabled and a 1 mA current source is applied between the BOOST and LNB output. If the LNB volts rise above 21 V, CAD will be set to 1. The CAD bit is reset if the LNB volts drop below 19.95 V.
- Bit 1 – Not used.
- Bit 2 TDET Tone Detect. When tone is enabled by whatever option, or if a tone signal is received from the LNB, TDET will be set to 1 if the tone appears at the LNB output. When the tone is disabled and no tone is received from the LNB, TDET is reset.
- Bits 3 to 7 Not used.

Table 8. Component Selection Table

Component	Characteristics	Manufacturer Device
C3	220 nF, 10 V <sub>MIN</sub> , X5R or X7R, 0402 or 0603	
C8, C9 <sup>b</sup> , C12 <sup>b</sup>	220 nF, 50 V, X5R or X7R, 0805	
C1, C4	100 nF, 50 V, X5R or X7R, 0603	
C2, C5	100 μF, 35 V <sub>MIN</sub> , ESR < 75 mΩ, I <sub>RIPPLE</sub> > 700 mA	ChemiCon: EKZE500ELL101MHB5D Nichicon: UHC1V101MPT Panasonic: EEU-FM1H101B
C7	22 nF, 10 V <sub>MIN</sub> , X5R or X7R, 0402 or 0603	
C10, C13	10 nF, 50 V, X5R or X7R, 0402 or 0603	
C11	0.68 μF, 25 V <sub>MIN</sub> , X5R or X7R, 0805	TDK: C2012X5R1E684K Murata: GRM21BR71E684KA88 Kemet: C0805C684K3PAC AVX: 08053D684KAT2A
C6	1.0 μF, 25 V <sub>MIN</sub> , X5R or X7R, 1206	TDK: C3216X7R1E105K Murata: GRM31MR71E105KA01 Taiyo Yuden: TMK316BJ105KL-T Kemet: C1206C105K3RACTU
D2, D3, D5	Schottky diode, 40 V, 1 A, SOD-123	Diodes, Inc: B140HW-7 Central Semi: CMMSH1-40
D4	TVS, 20 V <sub>RM</sub> , 32 V <sub>CL</sub> at 500 A (8/20 μs), 3000 W	Littelfuse: SMDJ20A ST: LNBTVS6-221S
D1	Schottky diode, 40 V, 3 A, SMA	Sanken: SFPB-74 Vishay: B340A-E3/5AT Diodes, Inc: B340A-13-F Central Semi: CSMH3-40MA
L1	33 μH, I <sub>SAT</sub> > 2.6 A, DCR < 90 mΩ	TDK: TSL1112RA-330K2R3-PF Taiyo Yuden: LHLC10TB330K Coilcraft: DR0810-333L
L2	220 μH, I <sub>SAT</sub> > 0.5 A, DCR < 0.8 Ω	TDK: TSL0808-221KR54-PF Taiyo Yuden: LHLC08TB221K Coilcraft: DR0608-224L
L3	1 μH, 1 A, DCR < 120 mΩ, 1206	Kemet: LB3218-T1R0MK Murata: LQM31PN1R0M00L Taiyo Yuden: LB3218T1R0M TDK: MLP3216S1R0L
R1 to R6	Determined by V <sub>DD</sub> , bus capacitance, etc.	
R7	15 Ω, 1%, 1/8 W	
R8	100 Ω, 1%, 1/8 W	
R9	30 Ω, 1/8 W	
R10	1 Ω, 1/8 W	

<sup>b</sup>Either C9 or C12 are used, but not both.

## Package ET 28 Pin MLP/QFN



For Reference Only  
 (reference JEDEC MO-220VHHD-1)  
 Dimensions in millimeters  
 Exact case and lead configuration at supplier discretion within limits shown

- △ Terminal #1 mark area
- △ Exposed thermal pad (reference only, terminal #1 identifier appearance at supplier discretion)
- △ Reference land pattern layout (reference IPC7351 QFN50P500X500X100-29V1M);  
 All pads a minimum of 0.20 mm from all adjacent pads; adjust as necessary to meet application process requirements and PCB layout tolerances; when mounting on a multilayer PCB, thermal vias at the exposed thermal pad land can improve thermal dissipation (reference EIA/JEDEC Standard JESD51-5)
- △ Coplanarity includes exposed thermal pad and terminals

**Revision History**

Number	Date	Description
16	February 15, 2012	Update Absolute Maximum Ratings
17	December 5, 2016	Updated product status to Not for New Design
18	June 5, 2017	Updated product status to Last-Time Buy
19	January 4, 2018	Updated product status to Discontinued
20	January 14, 2019	Minor editorial updates
21	January 20, 2020	Minor editorial updates

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DiSEqC™ is a trademark of Eutelsat S.A.

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